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	_	US- 6,829,175	12-07-2004	Tsai et al.	
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e for form 144s/PTU			Application Number	10/815,370		
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			Art Unit	2827		
(Use as many sheets as necessary)			Examiner Name	Trong Q. Phan		
2	of	2	Attorney Docket Number	MXIC 1571-1		
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